



TX-500

**Features**

- Low Phase Noise
- Low power consumption
- Output: HCMOS, Clipped Sinewave, PECL, True Sinewave
- Tight Tolerances
- Frequency range <sup>1</sup> of 6.4 - 160 MHz
- Standard Frequencies : 10, 12.8, 16.384, 19.44, 19.2, 20, 26 50, 77.76, 100, 122.88, 125, 155.52 MHz

**Applications**

- Base Station
- Test Equipment
- Communication Equipment
- Digital Switching
- Military

**Performance Specifications**

**Frequency Stabilities<sup>1</sup> (Standard TCXO)**

Parameter	Min	Typical	Max	Units	Condition	Options <sup>3</sup>
vs. operating temperature range (referenced to +25°C)	-1		+1	ppm	-40 to +85°C	
	-0.5		+0.5	ppm	-40 to +85°C	
	-1		+1	ppm	-20 to +70°C	
	-0.28		-0.28	ppm	-20 to +70°C	
Initial tolerance	-1		+1	ppm	at time of shipment, nominal EFC	
vs. supply voltage change	-0.2		+0.2	ppm	V <sub>S</sub> ±5% static	
vs. load change	-0.1		+0.1	ppm	Load ±10% static	
vs. aging / year	-1		+1	ppm	after 30 days of operation	

**Frequency Stabilities<sup>1</sup> (Stratum 3 TCXO)**

Parameter	Min	Typical	Max	Units	Condition	Options <sup>3</sup>
vs. operating temperature range (referenced to +25°C)	-0.8		+0.8	ppm	-40 to +85°C	
	-0.28		+0.28	ppm	-40 to +85°C	
	-0.8		+0.8	ppm	-20 to +70°C	
	-0.28		-0.28	ppm	-20 to +70°C	
Initial tolerance	-1		+1	ppm	at time of shipment, nominal EFC	
vs. supply voltage change	-0.2		+0.2	ppm	V <sub>S</sub> ±5% static	
vs. load change	-0.1		+0.1	ppm	Load ±10% static	
vs. aging / year	-1		+1	ppm	after 30 days of operation	
vs. aging / 20 years	-2.5		+2.5	ppm		Note: Stratum 3 per GR-1244-CORE: <±4.6ppm for all causes and 20years aging Holdover: <±0.37ppm over 24 hours
Over all tolerance	-4.6		+4.6	ppm		

## Performance Specifications

Supply Voltage (Vs)						
Parameter	Min	Typical	Max	Units	Condition	
Supply voltage (standard)	3.135	3.3	3.465	VDC		
Supply voltage (Option)	4.75	5	5.25	VDC		
Current consumption			35 100	mA mA	steady state @25°C, HCMOS, Clipped sinewave steady state @25°C, PECL	
RF Output						
Signal [standard]	HCMOS					
Load	13.5	15	16.5	pF		
Signal Level (Vol)			0.3	VDC	with Vs=3.3V and 15pF Load	
Signal Level (Voh)	2.6				with Vs=3.3V and 15pF Load	
Duty Cycle	40		60	%	@ (Voh-Vol)/2	
Rise and Fall time			5	ns	@15 pF 10 to 90 %	
Signal [Option]	Clipped Sinewave				Available < 40MHz only	
Load R	9	10	11	kOhm		
Load // C	9	10	11	pF		
Output power	0.7			V <sub>pp</sub>	@ 10kOhm // 10pF	
Signal [Option]	PECL				Available > 40MHz only	
Load	45	50	55	Ohm	to Vs - 2V	
Rise and Fall time			1	ns	20 to 80%	
Duty Cycle	45		55	%		
Signal [Option]	True Sinewave					
Load	45	50	55	Ohm		
Output power	0	3	6	dBm		
Frequency Tuning (EFC) 6.4 to 26 MHz						
Tuning Range	Fixed TCXO; No adjust				Option <sup>5</sup>	
Tuning Range	±8 ±5			ppm ppm		
Linearity	<10%					
Tuning Slope	Positive					
Control Input Impedance	10			kOhm		
Control Voltage Range	0.3	1.65	3.0	VDC	with Vs=3.3V	
Additional Parameters						
Phase Noise <sup>2</sup>		-87		dBc/Hz	10 Hz	@ 12.8 MHz HCMOS 3.3 V
		-119		dBc/Hz	100 Hz	
		-138		dBc/Hz	1 kHz	
		-151		dBc/Hz	10 kHz	
		-155		dBc/Hz	100 kHz	
		-155		dBc/Hz	1 MHz	
Jitter		0.2		ps RMS	@ 12 kHz to 20 MHz	
Phase Noise		-73		dBc/Hz	10 Hz	@ 100MHz HCMOS 3.3V
		-102		dBc/Hz	100 Hz	
		-132		dBc/Hz	1 kHz	
		-150		dBc/Hz	10 kHz	
		-158		dBc/Hz	100 kHz	
		-160		dBc/Hz	1 MHz	
Jitter		0.1		ps RMS	@ 12 kHz to 20 MHz	
Weight			2.0	g		
Processing & Packing	Handling & Processing Note					

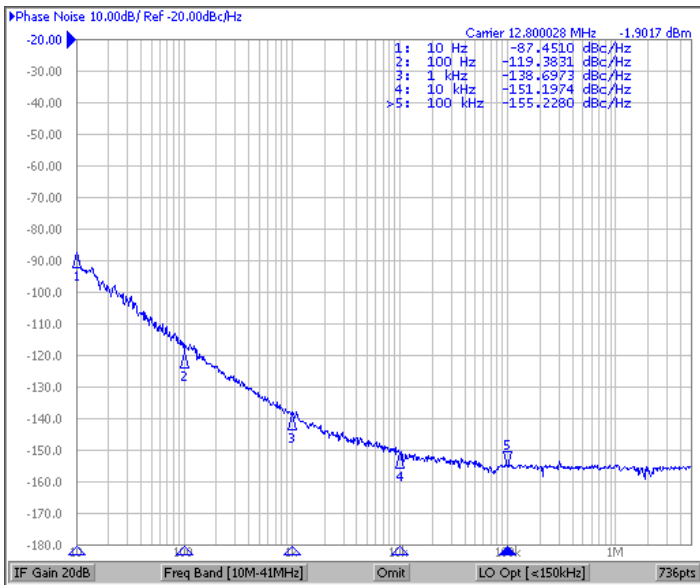
## Absolute Maximum Ratings

supply voltage (Vs)			6.0	V	with Vs=3.3 VDC
Output Load			50	pF	
Operable Temperature Range	-40		+85	°C	
Storage Temperature Range	-40		+105	°C	

## Typical Performance

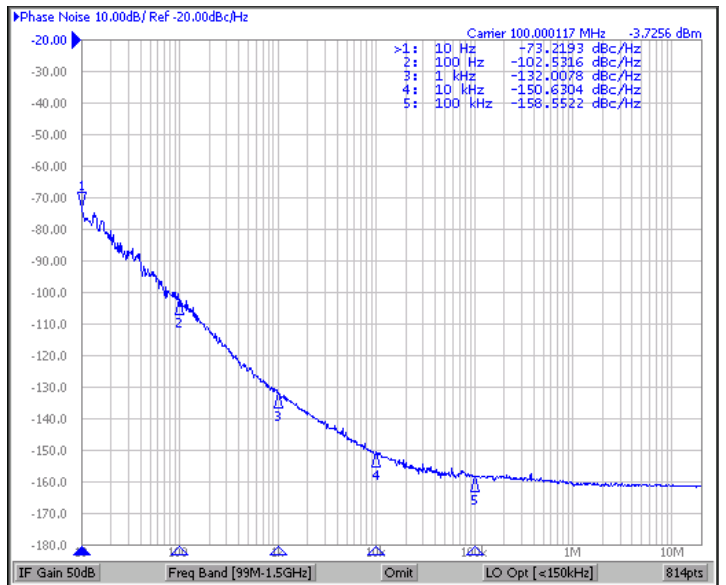
### Phase Noise

TX-500 @ 12.8MHz HCMOS



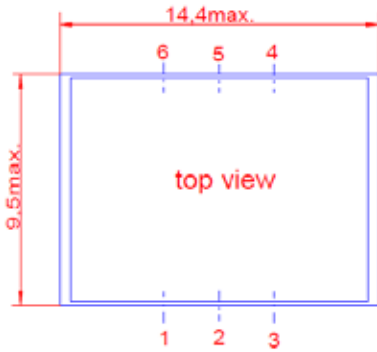
### Phase Noise

TX-500 @ 100MHz HCMOS

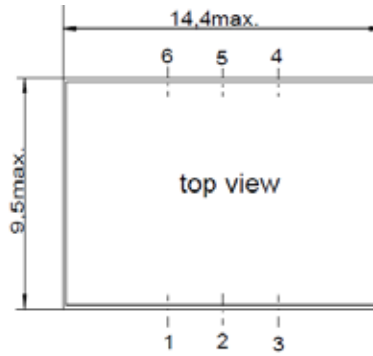


# Outline Drawing / Enclosure

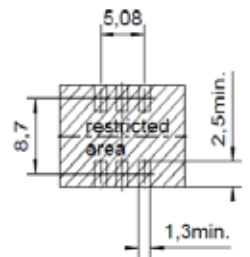
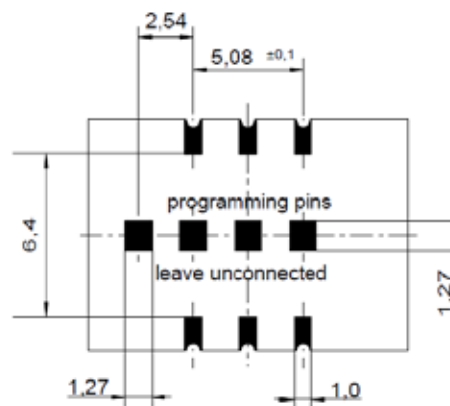
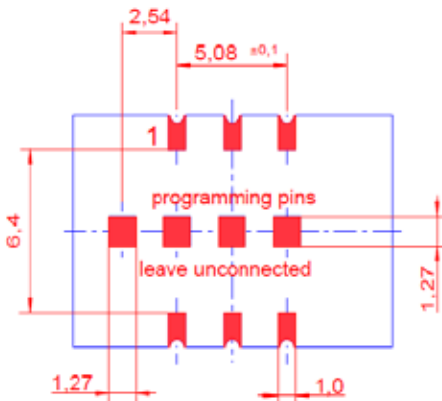
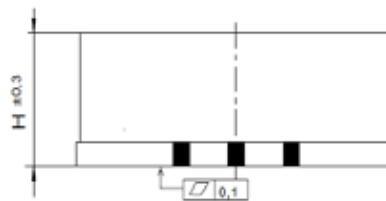
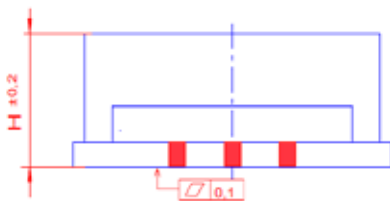
TX-500	
Type	Height "H"
G214B [Standard]	5.9
G214C [Option]	2.8
G286C [Option]	6.1



**G 214**  
H = 5,9 : G 214 B  
H = 2,8 : G 214 C  
H = 4,0 : G 214 D



**G 286**  
H = 5,9 : G 286 B  
H = 6,1 : G 286 C

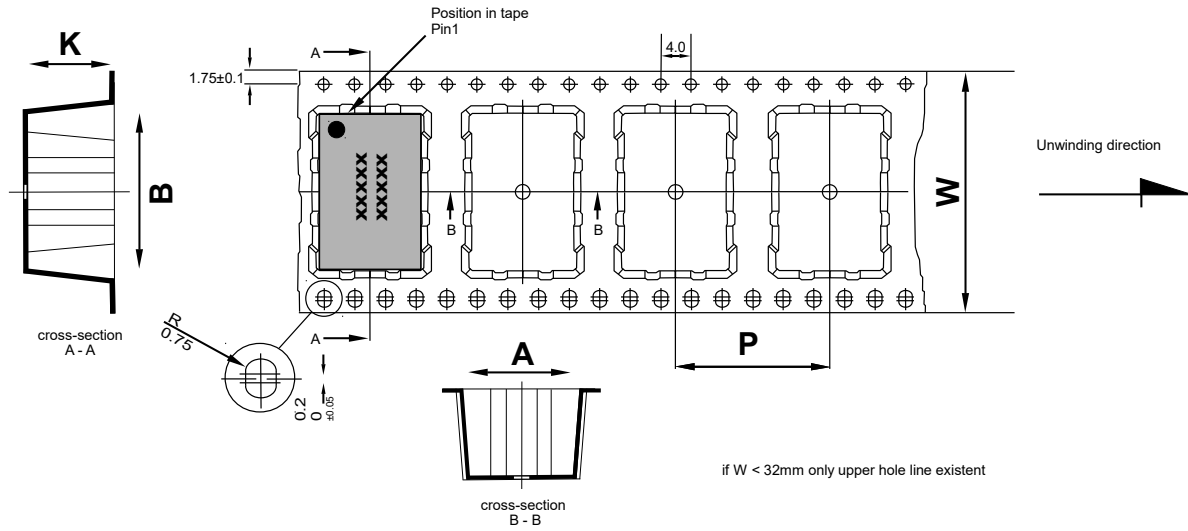


Padvorschlag  
land pattern  
recommendation

Pin Connections (CMOS, Clipped Sinewave, True Sinewave)	
1	Control Voltage Input (Vc) / N.C.
2	N.C.
3	Ground (Case)
4	RF-Output
5	N.C.
6	Supply Voltage Input (Vs)

Pin Connections (PECL)	
1	Control Voltage Input (Vc) / N.C.
2	N.C.
3	Ground (Case)
4	RF-Output
5	RF-Output_complementary
6	Supply Voltage Input (Vs)

## Standard Shipping Method (TX-500)



Dimension in mm:  
 A, B and K are dependent upon component dimensions  
 production tolerance complying DIN IEC 286-3

All dimensions in millimeters unless otherwise stated

Enclosure Type	Tape Width W (mm)	Quantity per meter	Quantity per reel	Dimension P
G214B / G286C	24	83.3	850	12
G214C	24	83.3	1700	12

## Recommended Reflow Profile

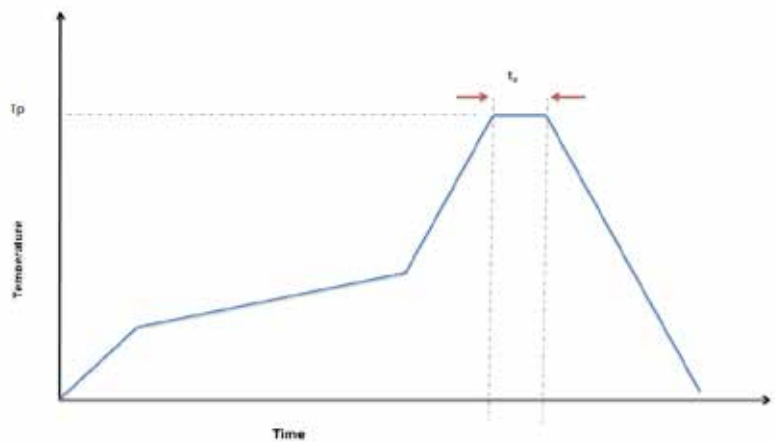
TP: max 250°C (@ solder joint, customer board level)

T<sub>p</sub>: max: 10...30 sec

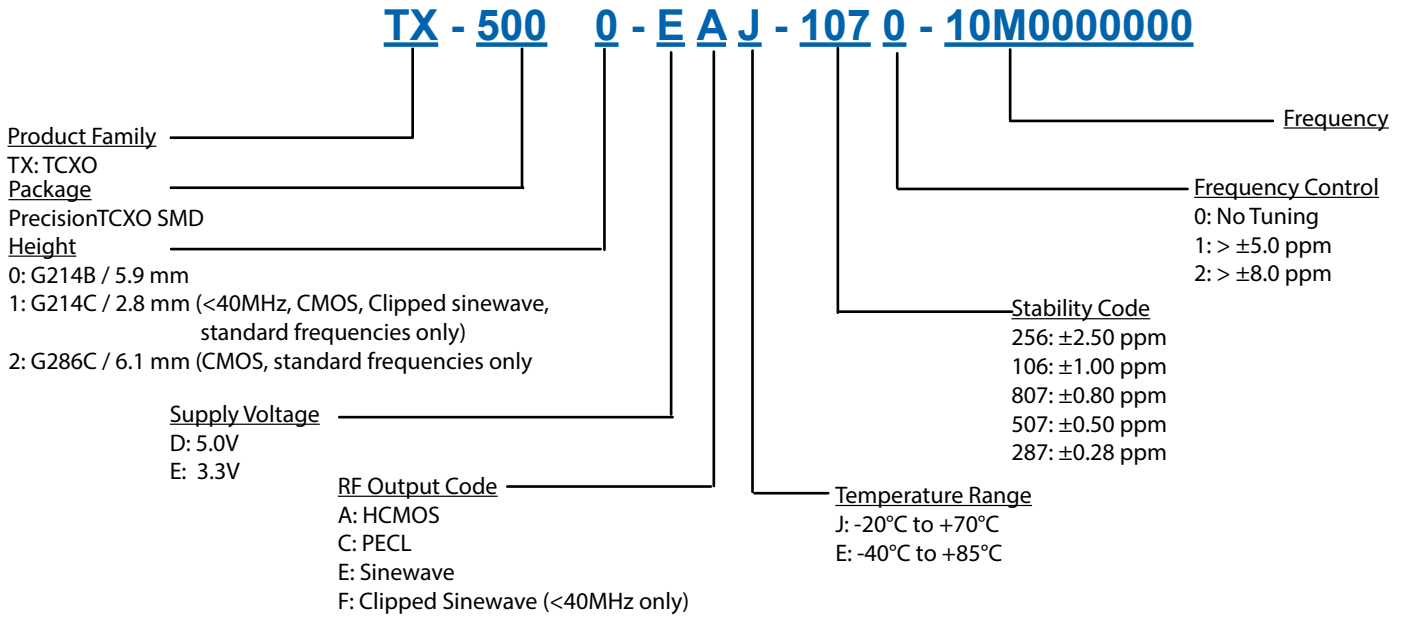
Additional Information:

This SMD oscillator has been designed for pick and place reflow soldering

SMD oscillators must be on the top side of the PCB during the reflow process.



## Ordering Information



**Notes:**

1. Contact factory for improved stabilities or additional product options. Not all options and codes are available at all frequencies.
2. Phase noise degrades with increasing output frequency.
3. Contact factory for availability.

Unless other stated all values are valid at typical conditions for supply voltage, frequency control voltage, load, temperature (25°C).

Subject to technical modification.



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